## **Optimization of TW XFELs**

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Physics and applications of high efficiency

free electron lasers workshop

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## **Presentation Outline**

#### 1. Physics of tapered FELs

1.1.Review of theory: 1-D, 3-D, and time dependent effects

#### 2. Optimization of tapered FELs

2.1.Improving the undulator - simulation

2.2. Tailoring the initial conditions

2.2.1. Fresh-bunch self-seeding - experiment

2.2.2.Pre-bunching - simulation

2.2.3.PWFA-FEL for TW-attosecond pulses - simulation

#### 3. Conclusions

## Why tapering to reach TW XFEL?



 Collective variable description gives analytic solution for power (BPN Opt Comm. 1984) described by single parameter q.

$$P_{sat} = \rho P_{beam} \qquad \rho = \frac{1}{\gamma} \left( \frac{I}{I_A} \left( \frac{K}{4k_u \sigma_x} \right)^2 \right)^{1/2}$$

- Typical numbers for XFEL:  $E_e=10 \text{ GeV}, I = 1 \text{ kA}, P_{beam}=10 \text{ TW}, \varrho = 10^{-3}$  $=> P_{sat} \sim 10 \text{ GW}$
- For TW we want~ 100x increase in efficiency to ~10 %

- **Tapered FEL** Κ High power **X-rays** Ζ Tapered section Exponential Growth (Post-Saturation) e-beam Exp  $10^{2}$ Growth  $10^{0}$  $P/\rho P_{beam}^{2}$  $\lambda = \frac{\lambda_u}{2\gamma_r^2} (1 + K^2)$ 10-4 Tapered 10 Section  $10^{-8}$ 10 20 30 50 40 z/L
- Resonant interaction can continue *past saturation* by tapering the magnetic field K(z) to match the e-beam energy loss γ(z)
- Questions are:
  - How do you optimize the taper to achieve the max efficiency?
  - What is the maximum achievable efficiency?





Power scaling in<br/>post-sat regime $P_{rad} = P_0 + \frac{P_1 \bar{z}}{E} + \frac{P_2 \bar{z}^2}{E}$  $P_2 = \left[\frac{Z_0}{8\pi} \left(\frac{K}{\gamma} \frac{\lambda_u}{\sigma_e}I\right)^2 (f_t \sin \psi_r)^2\right]$  $Sin \psi_r \propto \frac{|K'|}{E}$ Dominant for short<br/>undulators or large seedDominant for<br/>long undulatorsInitial Condition<br/>contributionTapering<br/>contribution





(1)

(2)

(3)

 $P_{rad} = P_0 + P_1 \bar{z} + P_2 \bar{z}^2$  $P_2 = \frac{Z_0}{8\pi} \left(\frac{K}{\gamma} \frac{\lambda_u}{\sigma_e} I\right)^2 \left(f_t \sin \psi_r\right)^2$ Power scaling in post-sat regime  $\sin\psi_r \propto \frac{|K'|}{E}$ Dominant for short Dominant for Tapering Initial Condition undulators or large seed long undulators contribution contribution Take home messages from 1-D theory 1.5 Normalized  $\delta\gamma$ 0.5Resonant phase  $\psi_r$  sets the speed of the taper and the size of the bucket \_ψ =π/8 : Trade-off between number of electron trapped and how  $\psi_r = \pi/4$ quickly the electrons are decelerated -0.50.5 0  $\psi/\pi$ Power scales like  $(f_t \sin \psi_r)^2$ \_\_\_\_\_f\_for cold beam Trapping Fraction 9.0 9.0 9.0 9.0 f for warm beam : Increasing the trapping by e.g. pre-bunching can increase P Power scales like  $I^2/\sigma_e^2 = I^2/\beta \epsilon_n$ 0.2 :. Brighter beam/smaller beta conducive to high efficiency  $0^{\mathsf{L}}_{\mathsf{O}}$ 0.2 0.5 0.1 0.3 0.4  $\psi /\pi$ 



## 1-D effects: trade-offs and design considerations

۷ ۲<sup>۷</sup>۷ [%]

۵ γ/γ<sub>0</sub> [%]

No tapering "Slow" tapering "Fast" tapering (c) **(a) (b)**  $\psi_r = 22.5^{\circ}$  $\overline{\psi_r} = 80^{\circ}$  $\psi_{r_{\bullet}} = 0$ Undulator K/K<sub>0</sub> 0.04 0.04 0.04  $z/L_q = 0$ 「%」<sup>0</sup>4% ∇ -0.02 0.02 0.02 0.02 [%] <sup>0</sup>//↓ 0 -0.02 ۵ ۱/۷<sub>0</sub> [%] -0.02 -0.04<sup>L</sup> -0.04 L -0.04 0.5 -0.5 0 Ψ/π 0.5 -0.5 0.5 -0.5 0 0 Ψ/π Ψ/π 0.6  $z/L_{g} = 25$ 0.5 [%]<sup>0</sup>¼⊀ ⊽ ۵ ۲<sup>۸</sup>۷ [%] 10 40 50 0 20 30 z/Lg -0.5 -3 -1<sup>L</sup> -1 -4<sup>L</sup> -1 -8L -1 0.5 0.5 -0.5 -0.5 0.5 -0.5 0 0 0 Ψ/π Ψ/π Ψ/π  $10^{-1}$ -23  $z/L_g = 40$ -6  $10^{-2}$ 0.5 -23.5 ∆ γ/γ<sub>0</sub> [%] ∆ γ/ץ<sub>0</sub> [%] Δ γ/γ<sub>0</sub> [%] -8 -24  $10^{-3}$ P/P beam -10 0 -0.5 -24.5 10 -12<sup>L</sup>  $P \propto z^2$ -25<sup>L</sup> -1<sup>L</sup> -1 10<sup>-5</sup> -0.5 0.5 -0.5 0.5 -0.5 0.5 0 0 0  $\Psi_{\rm r} = 0$ Ψ/π Ψ/π Ψ/π 10 -15 -35  $\Psi_r = \pi/8$ z/L<sub>a</sub> = 50 -16 0.5  $10^{-1}$ [%] <sup>0</sup>¼⊀ ∇ -37 **≥** −17  $P \propto e^{z/Lg}$  $\Psi_{\rm r} = 7\pi/16$ Δ γ/γ<sub>0</sub> [  $10^{-8}$ -18 -19 20 -0.5 10 30 50 0 40 z/L -20  $\bigcirc$ -38<sup>L</sup> -1<sup>L</sup> 0.5 0.5 -0.5 0 0.5 -1 -0.5 0 -0.5 0 Ψ/π Ψ/π Ψ/π "Slow" taper In 1-D theory, with a No tapering "Fast" taper has strikes the balance judiciously chosen taper efficiency is the larger net energy you can continue to between total same as saturation loss but smallest increase power by energy loss and fraction captured trapping fraction adding undulators

## 1-D effects: trade-offs and design considerations

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Note: for a fixed length undulator the resonant phase *variation* can be optimized and tends to increase along *z* when de-trapping becomes less important towards the end of the undulator



## 3-D effects: diffraction limits to the 1-D model



## Time Dependent effects: limits to the 1 frequency model



amplitude exceeds a certain threshold. This, in turn, will result in significant electron detrapping. Since it is the deceleration of the trapped electron bucket that provides the energy for the radiation in the case of tapered wigglers, detrapping will cause loss of amplification for the FEL signal"

S. Riyopoulos, C.M. Tang, Phys. Fluids (1988) "Chaotic electron motion caused by sidebands in free electron lasers"

**Sideband Instability** 

## Time Dependent effects: limits to the 1 frequency model



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## Simulation example: Multi-TW XFEL with an Advanced Gradient Undulator



C. Emma et al., "High efficiency, multi-TW X-ray free electron lasers", PRAB 19, 020705 (2016)

# **Overcoming the sideband instability with fresh bunch self-seeding**



- •GENESIS simulations show time dependent losses from sideband instability can be overcome using a large seed ( $P_{seed}/P_{noise} \sim 10^3$ ).
- •In a self-seeded FEL having a large seed comes at the expense of a large energy spread at the start of the seeded section.
- •Escaping the trade-off between seed power and energy spread requires **fresh bunch self-seeding.**





Brightness ratio	Average	Average filtered on e-beam energy	Peak
$B_{FBSS}/B_{SASE}$	12.5	15.5	35.4
$B_{FBSS}/B_{self-seeding}$	2.4	2.1	2.3,-

**Scientific Achievements** 

Short ~ 10fs pulses with 50 GW power and <10<sup>-4</sup> b.w.

~ 2\* increase in X-ray power / brightness compared to selfseeding

Table 6.1: Comparison between the average and peak brightness of the FBSS scheme with SASE and self-seeding at the same photon energy. The left column is an average without filtering the data based on the incoming electron beam energy. The middle column is an average of the data within the energy jitter window  $\Delta E/E_0 = 0.5\%$ . The right column is calculating using the best shot for each of the three schemes.



## **Tapered FELs with pre-bunched beams**



#### Future studies: TW-Attosecond pulses from PWFA-FEL + eSASE

I [kA] Chicane X-rays FACET-II laser Energy modulated FT-limited e-beam TW-level Tapered **PWFA** Wiggler Attosecond undulator Current Single spike 10 GeV modulated Hard X-rays 10 kA e-beam on 10s 0.1 % dE/Eof nm scale 20 pC

For single spikes you want  $\sigma_z \sim L_{coop}$ 

For FACET-II PWFA case we have  $L_{coop} = \lambda_r / \lambda_u L_G \sim (1 \text{ nm}/1 \text{ cm}) * 30 \text{ cm} = 100 \text{ as}$ 

Coming out of the PWFA we have  $\sigma_z \sim 800$  as so we need laser-based compression to give factor 8 reduction in spike length.

Modulation (delta gamma) scales like sqrt(laser power) see Zholents PRSTAB

See J. Duris talk tomorrow

#### **GENESIS SIMULATION**





**Electron Beam** 



- Simulation assumes current profile from slide before. The undulators are from LCLS-II SXR. ۲
- Power reaches 2 TW in 5 m (1.5 undulators) with FWHM 42 as and 46 eV bandwidth. The time-۲ bandwidth product is 1.93 eV\*fs, very close to the Fourier limit (1.8 eV\*fs). After super radiant spike saturates the SASE from the shoulders keeps growing exponentially and eventually broadens the pulse.
- Adding more undulators SASE will grow behind the leading spike spoiling the coherence. Maybe this ۲ can be suppressed with faster tapering, studies are ongoing.

## Conclusion

- (1) We studied **undulator tapering strategies** to increase the efficiency of XFELs and reach TW peak power levels.
- (2) **Diffraction** and the **sideband instability** were identified as the fundamental processes which limits the efficiency of tapered XFELs.
- (3) We presented the design of an **advanced superconducting undulator** for maximal energy extraction (> 10 %) in the shortest possible undulator length (100 m) to overcome diffraction limits.
- (4) We presented a solution to the sideband problem, the **fresh bunch self-seeding method**, and demonstrated it experimentally at the LCLS.
- (5) Our demonstration of FBSS shows a **brightness increase** of 12/2 times compared to SASE / regular self-seeding.
- (6) We have studied a combination of pre-bunching and FBSS as a sort of **"ideal system"** for a TW level tapered XFELs. Results from 1-D sims are encouraging, 3-D sims to come.

#### What Next?

(1)Detailed studies of high efficiency/tapered FELs with advanced accelerator beams.

(2)More exploratory studies of advanced schemes: e.g. tapered eSASE, superradiance, tailored beam profiles, pre-bunching...



## **Backup slides**



## Sideband suppression via gain modulation



FIG. 5. (Top) Undulator taper profile for a gain modulated tapered FEL. The modulation section at  $N_u = 750$  changes the synchrotron frequency and damps the sideband growth (see Fig. 6). (Bottom) The trapping fraction drops after the modulation section but remains constant compared to the unmodulated case which suffers from severe sideband-induced detrapping after  $N_u = 1500$ .



FIG. 6. Radiation spectrum (top) and temporal profile (bottom) with and without gain modulation showing sideband reduction for a gain modulated high efficiency FEL. The ratio of sideband to total power is 55% in the unmodulated case and 4% in the modulated case.